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Bachelor in Micro and Nanotechnologies Engineering Sciences

Development of Plasmonic Nanosandwiches for Biosensing Applications

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"No one should be ashamed to admit they're wrong, which is but saying, in other words, that they are wiser today than they were yesterday."

Alexander Pope

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Resumo

Foram estudadas estruturas compostas por dois discos de ouro de diâmetros diferentes, separadas por uma camada fina de alumina, para biodeteção de proteínas. O disco superior será menor, uma vez que tem um comprimento de decaimento mais curto (e como tal, maior sensibilidade), enquanto que o disco inferior de maior dimensão irá dar um sinal de alta intensidade devido à sua maior interação com a luz. A interação entre os dois discos acontecerá através da hibridização plasmónica. A caracterização das amostras consistiu na análise morfológica por microscopia eletrónica de varrimento (SEM), a resposta ótica foi estudada experimentalmente e por simulações de domínio do tempo de diferença finita (FDTD) e também analisada a distribuição do campo elétrico em três tipos de estrutura. Foram estudadas estruturas com o disco superior numa posição central relativamente ao disco inferior tal como na extremidade do mesmo, e também o efeito da espessura do óxido (3 e 6 nm). O pico de baixa energia é sobretudo devido a um modo plasmónico dipolar na separação dos discos metálicos, enquanto que o pico de alta energia é dado pela contribuição do modo da separação e pelo dipolo resultante da estrutura. A estrutura com menor separação e com o disco centrado em relação ao disco inferior tem um aumento do campo elétrico em redor da mesma maior e deverá ser esta a utilizada como biossensor.

Palavras chave: Biossensor, ressonância plasmónica de superfície localizada, hibridização plasmónica, litografia coloidal

Abstract

Structures composed of two gold disks with different diameters and separated by a thin alumina layer were studied for protein biodetection. The small top disk will be used as the biosensing element since it has a shorter decay length (and thus, it has a higher sensitivity) whereas the big bottom one will give a high signal due to its bigger interaction with light. The interaction between both disks will happen through plasmon hybridisation. The samples were prepared using colloidal lithography and material deposition was made through an electron beam assisted evaporation system. A fabrication method was developed to spatially isolate the bottom disk from the sensing medium to fully exploit the small disk's higher sensitivity. Sample's characterisation consisted in a morphologic analysis by scanning electronic microscopy (SEM), the optical response was studied experimentally and by finite-domain timedifference (FDTD) simulations and also the electric field distribution was analysed in three types of structures. Structures with the upper disk centred relative to the lower disk and at the edge of it. The oxide's thickness effect was studied (3 and 6 nm). The low energy peak is mainly given by a plasmonic gap dipole mode, whereas as the high energy peak is given by a contribution from a gap mode and the structure's overall net dipole. The structure with a smaller separation and the top disk centre regarding the bottom disk was found to have a higher electric field enhancement around it and should be the one to be used as a biosensor.

Keywords: Biosensor, localised surface plasmonic resonance, plasmon hybridisation, colloidal lithography

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List of Abbreviations

FDTD HE LSPR PAX PDDA PMMA PSNP PSS SEM SPP	Finite-difference time-domain High energy Low energy Localised surface plasmon resonance Polyammonium chloride Poly(diallydimethylamminium chloride) Poly(methyl methacrylate) Polystyrene nanoparticle Poly(sodium-4-styrnesulfonate) Scanning electron microscopy Surface plasmon polariton
UV XPS	Ultraviolet
XP3	X-ray photoelectron spectroscopy

List of Symbols

\vec{E}	Electric field			
$\overline{\vec{p}}$	Dipole moment			
0	Degree			
°C	Degree Celsius			
Å	Ångstrom			
AI	Aluminium			
Al ₂ O ₃	Alumina			
Au	Gold			
cm	Centimetre			
i	Imaginary unit			
kV	Kilovolt			
me	Effective electron mass			
min	Minute			
mm	Milimetre			
mTorr	Millitorr			
Ν	Density of free electrons			
N ₂	Nitrogen			
nm	Nanometre			
O ₂	Oxygen			
pА	Picoampere			
q	Elementary charge			
rpm	Rotations per minute			
S	Second			
sccm	Standard cubic centimetre per minute			
SiO ₂	Silica			
Ti	Titanium			
W	Watt			
γ	Electron collision frequency			
3	Dielectric function			
E 0	Dielectric permittivity			
ω	Angular frequency			
ω _P	Bulk plasma frequency			

1. Motivation and Objectives

Metallic nanostructures have been widely studied due to their interesting optical response, effectively enhancing the electric field near the structure's surface. Many structures have been studied from simple nanospheres¹, nanorings² or nanodisks^{3–5}. It is possible to include dielectric materials in the fabrication process to make more complex structures as nanoshells⁶, nanocups⁷ or nanosandwiches^{8–10}, usually rendering two metallic structures physically separated, making a metal-insulator-metal configuration. This configuration has an additional field enhancement and confinement¹¹ which could lead to interesting developments. Some of the applications of this field confinement relate to waveguiding materials¹², photovoltaic devices^{13,14}, development of metamaterials^{15,16} and sensitive biosensing^{5,17}.

As far as metallic nanoparticle-based biosensors go, they can be used with different physical principles. For instance, gold is a highly conductive metal with catalytic properties, being suitable for electrochemical sensing¹⁸. It is also common to use such particles for signal amplification as generally, some of them exist in low concentration in body fluids, for instance¹⁹. Other sensors rely on fluorescence. Extremely small particles, called nanoclusters (up to 100 gold atoms¹⁸), have fluorescent properties due to their size, as they behave like individual molecules. Compared to other fluorescent materials, these nanoclusters show high photostability and biocompatibility^{18,20}.

Localised surface plasmon resonance-based biosensors are also a viable approach. This resonance happens at different light wavelength according to the metallic nanoparticle's size, shape, surrounding environment, amongst other factors¹⁸. The readout of such biosensors is based on a peak shift when the desired protein² or cell²¹ is located and bound to the structures, making the surrounding environment's refractive index different. They can reach sensitivities of around 1500 nm/refractive index unit, using a metal-insulator-metal configuration²².

This work intends to develop a series of nanostructures all over a substrate's surface using a wellestablished nanofabrication method²³. Each structure comprises two stacked metal disks, spatially separated by a thin insulator layer. The top disk will act as the analyte sensor as it has a smaller diameter compared to the bottom one to be more sensitive in the presence of one molecule. The higher sensitivity arises from the shorter decay length that localised surface plasmon resonances have compared to the propagating surface plasmon resonances. The same would happen when comparing two nanoparticles with one dimension (diameter in this case) shorter than the other's diameter, the former will have a shorter decay length²⁴. The bottom, big disk will serve as an antenna to help produce a high, measurable signal. This disk will be isolated from the sensing region as suggested by Figure 1.1 These two disks will interact with one another through their individual plasmonic responses. The biosensor should give a readout based on a peak shift on its extinction spectrum when surrounded by substances with different refractive indices.



Figure 1.1 – A) Cross section of the ideal structures to be developed. B) Cross section of the structures with proteins (in blue) to be detected bound only to the upper disk.

2. Introduction

2.1. Plasmonics

Extensive research has been made in the past years on metal nanoparticles and their unique optical properties, as well as the interaction between two particles that are a few nanometres apart from each other^{3,4,7,8}. Metals are shiny and reflective to the human eye because the frequency of the incident light can be matched by the material's free electrons' oscillations, thus creating a screening effect that does not allow the wave to propagate through the material¹⁶. However, for light above specific frequencies, the free electrons in the metal are unable to oscillate according to the frequency of the incident light, allowing light to propagate through the material at high frequencies. This plasma model does not take into account the interband transitions that happens in the visible frequencies in noble metals, limiting this approach to these frequencies¹¹.

The frequency at which such propagation occurs is designated as bulk plasma frequency, $\omega_{\rm P}$, and it is given by²⁵:

$$\omega_{\rm P} = \sqrt{\frac{Nq^2}{\varepsilon_0 m_{\rm e}}} \tag{1}$$

Where *N* is the density of the free electrons in the metal, *q* the elemental charge, ε_0 the dielectric permittivity and $m_{\rm e}$ the electron effective mass. Another result of this ability of the electrons to oscillate accordingly to an external electric field is the variability of the dielectric function $\varepsilon(\omega)$, described by Drude model (only considering the free electronic response) with a high frequency part (ε_{∞}) due to the bound electrons for noble metals²⁵:

$$\varepsilon(\omega) = \varepsilon_{\infty} - \frac{\omega_{\rm P}^2}{\omega^2 + i\gamma\omega}$$
(2)

where γ is the electron collision frequency (around 100 THz at room temperature¹¹) and quantifies the oscillation damping. The real part of a metal's dielectric function for frequencies below $\omega_{\rm P}$ is negative, meaning that the material will act as a conductive material¹¹.

2.1.1. Localised Surface Plasmonic Resonance

When dealing with nanometric particles, there will be another influence from the nanoparticles' surface that should be taken into account. Considering a simple nanosphere, a time dependent electric field interacts with the nanoparticle, in a way that makes the conduction electrons oscillate collectively accordingly to the incident light. As the electrons go away from their natural position, the atoms' nuclei will exert an electrostatic attraction on the electrons, leading to a resonance. This resonance results in a field enhancement just outside the particle (near-field). Since these oscillations do not propagate, this phenomenon is called localised surface plasmonic resonance (LSRP).¹¹

If the incident light has a wavelength much longer than the nanoparticle size (as suggested by Figure 2.1), the electric field on the nanoparticle can be considered constant (quasi-static approximation). If

this happens, all the electrons will move accordingly to the nanoparticle's surface, leaving a net positive charge on the other side, creating a dipole. This dipole will depend on the nanoparticles' polarisability, α . This term reflects the electrons' tendency to displace when excited with an external electric field and creating the dipole, which is given by¹¹:

$$\alpha = 4\pi a^3 \frac{\varepsilon - \varepsilon_m}{\varepsilon + 2\varepsilon_m} \tag{3}$$

Being *a* the radius of the nanosphere, ε the dielectric function of the nanoparticle and ε_m the dielectric constant of the surrounding medium. Keeping in mind that the dielectric function of the metal varies with the incident light frequency, the polarisability can get a maximum value and thus, resulting in a resonance enhancement when the denominator reaches a minimum $(\text{Re}[\varepsilon(\omega)] = -2\varepsilon_m)^{11}$. So, it is possible to understand that there is a frequency for which the dielectric function of the metal is such that fulfils this condition, and a LSPR is obtained.



Figure 2.1 - Dipole \vec{p} created on a spherical metal nanoparticle due to the incident light with a wavelength such that is longer than the particles' size.

When a LSPR is excited, a dipole is created, and this induces an electric field on the nanoparticle's surroundings (Figure 2.2). Near the particle's edge, the accumulated charges on one end, alongside with the absence of charges in the other, will create an electric-field enhancement^{4,26}, where the magnitude of this near-field at the surface is given by²⁵:

$$E_{surface} = \frac{3\varepsilon_m}{\varepsilon + 2\varepsilon_m} E_0 \tag{4}$$

where E_0 is the magnitude of the incident light's electric field.

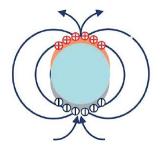


Figure 2.2 - Representation of the electric field (in the form of field lines) created due to the electrons' movement to the particle's surface when excited by light. Adapted from ²⁷.

Another consequence of this LSPR is the scattering and absorption enhancement that also occurs. The plasmons can decay radiatively (leading to a far-field scattering) or not (leading to absorption)⁴. Absorption occurs more efficiently in small particles whereas a bigger particle scatters light more efficiently²⁸. Regardless of what happens, both these effects contribute for light extinction and this

reflects on the extinction spectra of a nanostructure. At the resonance frequency, the spectra shows a high intensity peak^{11,29} and these measurements are then representative of the plasmon oscillations and the field enhancement²⁵.

Although equations (3) and (4) apply only for spherical nanoparticles, the same phenomena occur on other shaped particles. There should be a correction on the polarisation since it differs for each direction as the electrons could have more space to oscillate along one direction compared to another¹¹. A disk, for example, can be considered as a flat ellipsoid, and will have different resonance frequencies should it be excited perpendicularly to the flat surface or parallel to it.

2.1.2. Plasmon Coupling in Closely Located Particles

When a metal nanoparticle is excited with light at a certain frequency, the near-field is enhanced. In case two separate nanoparticles are in close proximity, both near-fields can interact with each other and enhance it even more²⁵. Two metal nanoparticle structures can be fabricated with the particles being on the same plane^{3–5,23} or as a stacked structure using an insulator layer to separate them^{8,30}. This last one refers to metal-insulator-metal nanosandwiches, but other type of geometries using this kind of separation can be achieved^{6,7,31}. The electrons' oscillations of the two particles become coupled. A good example of this is when spherical gold nanoparticles in solution aggregate, the extinction spectra red-shifts^{25,28}.

In 2003, Prodan and his colleagues developed a model that could explain the plasmonic response for complex shaped nanostructures similar to the hybridisation that occurs in molecular orbital theory⁶. They have studied how could a nanoshell response be understood as a combination or hybridisation of two simpler structures, a nanosphere and a nanovoid. The 'individual' plasmons of both sphere and void will interact with each other since there is a finite metal thickness and will result in a lower energy symmetric plasmon and a higher energy antisymmetric plasmon. Following this work, this model was successfully applied to metal dimers to determine the system's resonance frequencies³¹.

2.1.3. Surface Plasmon Polaritons and Gap Modes

When there is a flat interface between a dielectric and a metal, surface plasmon polaritons (SPPs) can arise. These are electromagnetic excitations that propagate along the interface and the magnitude of the electric field decays evanescently perpendicularly to the interface. Should there be two metal-insulator interfaces with a distance between them smaller than the SPP's decay length (in a metal-insulator-metal structure, being the insulator a thin film of a few nanometres), both interfaces' SPPs can interact with each other¹¹, leading to plasmonic gap modes. An interesting result of this phenomenon is the strong confinement of the electromagnetic field inside the insulator layer.

2.2. Nanofabrication

To make structures in the nanometric scale, one must resort to proper techniques. These techniques, on how they act to build these structures, can be designated by bottom-up or top-down.

Bottom-up fabrication techniques are based on the assembly of small building blocks to achieve the desired structure, the same way as one would build a house by assembling bricks as desired. However, since it is not possible to pick an atom or molecule and place it wherever we want, there must be another way of doing this. Self-assembled monolayers are one type of structures built this way. It is a technique that allows to make a thin film of a certain material onto a surface as the molecules spatially arrange themselves spontaneously to form such structure, reaching the energetic equilibrium³². Sulphur has a great affinity with transition metal surfaces in general (especially with gold). This interaction with gold is one of the most studied, and more specifically, alkanethiolates on gold. The sulphur head of these molecules can attach to the metal's surface while the carbon chain interacts with other chains to arrange themselves through Van der Waals and dipole-dipole interactions among to create a well-organised layer³³. Polystyrene microspheres (up to 5 μ m) dispersed in solution can also self-assemble themselves into an organised lattice, promoted by electrostatic interactions and capillary forces. In case the solution has a low concentration or it is dried quite fast, the particles will be dispersed through the surface as they cannot organise in those conditions³³.

A top down approach is one that starts from a big piece of material and someone carves the material to the desired shape, much like the art of sculpting, where the artist starts with a big rock. Electron beam lithography is one example³⁴. This technique relies on focusing an electron beam against an electron sensitive material such as PMMA. Wherever the beam hits this polymer, it will alter the polymer and, for example, can make that area more soluble and easier to remove³³, leaving a predetermined pattern on the polymer with high resolution and controlled spacing and dimensions⁴. When part of the polymer is removed, it can be possible to deposit the desired material into the voids using a lift-off approach^{3,4}. The price of pattern fidelity is the difficulty of making said patterns over a large sample area, and for that, time consuming, rendering further extinction characterisations much more difficult³. It also needs vacuum so that the pattern can actually be correctly transferred from the source to the substrate³³.

2.2.1. Hole-Mask Colloidal Lithography

One can use other techniques based on a colloidal solution to make a lithographic mask, hence the name colloidal lithography. This kind of techniques consist in using micro or nanospheres that, when deposited on top of a surface, the shape and size of the particles as well as the surface chemistry and its interaction with the particles will allow the self-assembly of a 2D periodic array all over the surface. Since it uses the spontaneous self-assembly process of the particles, colloidal lithography techniques are quite simple and relatively inexpensive³⁵.

A variant method of a colloidal lithography technique was developed by Fredriksson *et al.* in 2007, named hole-mask colloidal lithography²³. The particles used in this variation are charged beads (generally the negatively charged polystyrene) on top of a polymeric film. This polymer will serve as a sacrificial layer and can be deposited through a spin-coating process. On top of the polymer, three layers of polyelectrolytes are added on top to better adhere the polystyrene nanoparticles (PSNPs) to it. An etch resistant material such as titanium (Ti) or aluminum (Al) is deposited and then, the PSNPs are tape-stripped, taking away the particles and the titanium that was on top of them. This results in an etch mask

with holes shaped and positioned the same way as the PSNPs, resulting in the name of this technique. After this removal step is done, an etching step is followed to selectively remove the sacrificial layer beneath the mask turning possible the deposition of the desired materials.

Should the deposition be made at a normal direction, the shape of the nanostructures produced should resemble a cylinder. However, this is not the case since the materials show a sidewall angle (because the holes are being closed) when deposited through a physical vapour deposition technique, rendering a conical shape to the structures³⁶. The process is illustrated schematically in Figure 2.3 as well as some structures possible to fabricate.

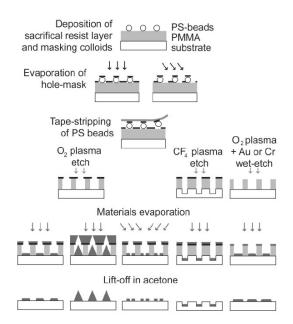


Figure 2.3 - Schematic of the hole-mask colloidal lithography process. On the bottom of the figure, it is shown some possible structures fabricated with this method, being the standart disks, while varying the thickness of material can result in cones, and varying the deposition angle in metallic dimers. Reproduced from ²³.

This sidewall angle varies depending on the material deposited. It can be relatively small for gold (about 12 °) and aluminium (15 °) while for titanium is slightly bigger (29 °)³⁶. This angle can be higher, reaching 47 ° when depositing SiO₂ through a thermal evaporation procedure¹⁰. Kontio and his co-workers used a physical vapour deposition technique and obtained a mask which eventually closed during the deposition³⁶.

This is not ideal if one desires to fabricate cylindrical nanodisks, however, the fact the holes could be closed during deposition is by itself interesting. Frederiksen *et al.* developed a method to reduce the size of the holes existing in the mask, turning possible the deposition of smaller disks in a certain position relatively to the first ones. It consists in depositing titanium with a high deposition angle to ensure that the deposition only occurs on the mask while the sample is rotating to promote homogeneity and circularity of the holes³⁷. This technique allows to fabricate disks pairs with one disk bigger than the other, and it possible to deposit disk pairs with same interparticle distance as suggested by the third structure in the bottom in Figure 2.3. Both cases allow the proximity between two nanostructures which LSPRs will interact with each other, promoting the plasmonic coupling.

3. Materials and Methods

3.1. Nanostructures Fabrication

The general fabrication steps are schematically reproduced in Figure 3.1, with the details of each step described as follows.

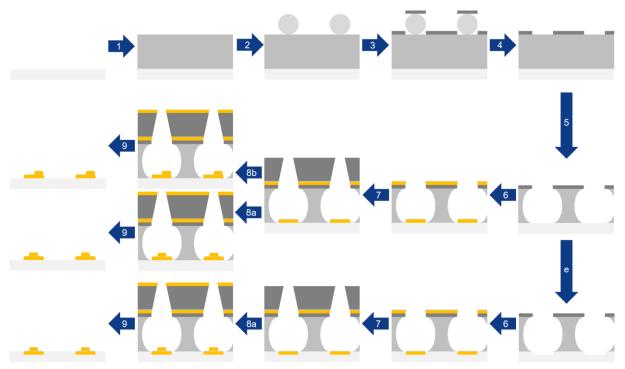


Figure 3.1 – General schematic of the nanosandwiches fabrication, starting with clean substrates. The included steps are: 1 – PMMA spin-coating; 2 – Polyelectrolyte layer and polystyrene particles deposition; 3 – Etch mask deposition; 4 – Particles tape stripping; 5 – PMMA etching; 6 – Au and Al layer deposition, followed by Al oxidation; 7 – Hole shrinking using an oblique deposition; 8 – Second Au layer deposition at a) 0 ° and b) 6 °; 9 Lift-off. The quartz samples also included an extra substrate etching step (e).

3.1.1. Substrate Cleaning

Samples were prepared on glass substrate (25 mm Ø #2, Menzel-Gläser) for general purposes and on quartz substrate when used in the Pegasus etching machine. They were firstly cleaned by wiping with acetone and then dried with a flow of N₂. After that, the substrates were exposed to a plasma treatment (Table 3.1) to remove the residual organic material on the surface.

3.1.2. Sacrificial Layer Spin-coating

After the cleaning procedure, the sacrificial layer was spun-coated onto the surface (step 1 on Figure 3.1). PMMA (polymethyl methacrylate with molecular weight (M_w) of 495 kDa, 4% in anisole, micro resist technology GmbH, Germany) was used on a spinner (SPS Europe, Spin 150 wafer spin processor) for 1 min at 3000 rpm and an acceleration of 1000 rpm/s. After this, the substrates were immediately transferred to a hot plate to bake at 180 °C for 5 min.

3.1.3. Polyelectrolyte Layer and Polystyrene Particles Deposition

Step 2 of Figure 3.1 is as follows. The samples were exposed to a UV-ozone (ProCleanerTM Plus from BioForce Nanosciences, US) treatment for 5 min to improve the surface chemistry. Three polyelectrolytes were added sequentially with a pipette, letting each one to self-assemble for 30 s followed by a rinsing step with deionised water for 30 s and a drying step with a flow of N₂. The polyelectrolytes used were 2% wt. PDDA (poly(diallydimethylammonium chloride) with M_W between 200 000 and 350 000 from Sigma-Aldrich, Denmark), 2% wt. PSS (poly(sodium-4-styrenesulfonate) M_W 70 000 from Sigma-Aldrich, Denmark) and 5% PAX-XL60 (polyammonium chloride from Kemira Miljø, Denmark), all diluted in deionised water. Finally, a 0.2 % w/V sulphate latex polystyrene bead colloidal suspension (120 nm cv = 5.1 %, 140 nm cv = 5.9 %, Invitrogen Molecular Probes, ThermoFisher, US) was also pipetted to the surface, and letting it stay for 2 min, rinsing it afterwards with deionised water for 1 min to remove the excess particles and the samples were then dried with N₂. The samples were again subjected to a UV-ozone treatment for 90 s.

3.1.4. Metal Depositions

All metal depositions were made through an electron beam assisted physical vapour deposition system (POLYTEKNIK, DK, Cryofox Explorer 400 GLAD with a FERROTEC, DK, E-Beam insert).

Titanium was generally used as an etching mask although aluminium was used on quartz samples (step 3 in Figure 3.1). In either case, a 20 nm thick film was used, evaporated at a rate of 0.5 Å/s for Ti and 1 Å/s for Al. The samples were rotated at 3 rpm to ensure homogeneity. The particles were then tape stripped with an electrostatic tape (step 4 in Figure 3.1) and the samples were plasma etched according to Table 3.1 (step 5).

The first Au disk had a thickness of 20 nm deposited at a rate of 0.5 Å/s and it was followed by the deposition of a thin layer of Al (1.5 nm thick) at 0.3 Å/s. The vacuum was broken so to be able to oxidise the Al with an O_2 plasma treatment (Table 3.1) to obtain a 3 nm thick film of Al₂O₃, according to ⁸ (step 6 in Figure 3.1). To make a 6 nm thick oxide film, a second deposition-oxidation step of Al was made after the oxidation of the first layer.

In order to make smaller disks, the holes were shrunk using Ti according to Frederiksen *et al.*³⁷ (step 7 in Figure 3.1). Using a large oblique angle, it is possible to ensure that the material is only deposited on top of the mask and not on the actual structures. This deposition occurred in two steps, being the first a 70 nm thick film deposited at 70 ° and the second a 20 nm thick layer deposited at 60 °. Both depositions were made at a rate of 0.5 Å /s with the samples rotating at 3 rpm. This two stepped process is to ensure that it is possible to shrink the holes evenly since the shrinking rate of a one stepped process tends to zero and the disks become less circular³⁷.

Finally, step 8 is the second Au disk deposition. It was deposited a 20 nm thick film at a rate of 0.5 Å/s. This disk could be deposited at an angle to break vertical symmetry (mostly 0 ° and 6 ° were studied, corresponding to the steps 8a and 8b respectively).

3.1.5. Samples Development

The masks were lifted off using an acetone sonication for 5 min and they were rinsed with isopropanol. They were finally dried with compressed N_2 (step 9 on Figure 3.1).

3.1.6. Quartz Samples Etching

The extra step (step e in Figure 3.1) was performed on quartz substrates to use only the top disk as the sensing particle as it was necessary to spatially isolate the bottom disk. For that, holes on quartz samples were etched using Pegasus ICP (DRIE) from STS. 40 sccm of CF₄ flowed through the chamber with a power of 450 W and a process pressure of 20 mTorr for 90 s. Quartz samples and AI masks were used in this machine (soda lime glass and other metals were not allowed in this system).

3.1.7. Oxygen Plasma Treatments

All the cleaning, PMMA etching and oxidation steps using O₂ were carried out on Vision 300 MK II, Advanced Vacuum. Each process parameter is described on Table 3.1.

Table 3.1 - Oxygen plasma treatment parameters	for all processes.
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Step	Time [min]	RF power [W]	Process pressure [mTorr]	O ₂ flow [sccm]
Sample cleaning	12	50	25	40
PMMA etching	15	100	25	40
Al oxidation	0.5	35	70	60

3.2. Samples Characterisation

3.2.1. Scanning Electron Microscopy

The structures' morphology was analysed through a SEM (Magellan 600 from FEI). The working distance was approximately 4 mm, the working potential of 5 kV and nominal beam current of 50 pA. To avoid charging, all samples were covered in a 5 nm thick titanium layer, except where noted. ImageJ was used (refer to Annexe A – ImageJ Processing for details) afterwards to obtain data about the disks' dimensions and spacing and treated with a MATLAB script developed, shown in Annexe B – MATLAB code.

3.2.2. Extinction Measurements

Extinction spectra were obtained using a spectrometer (Shimadzu UV-3600 UV-VIS-NIR). Dual beam measurements were performed with a clean glass slide as reference, using a slit width of 8 nm and sampling intervals of 1 nm. The structures were facing the light source and the extinction was measured on the backside of the substrates.

3.2.3. FDTD Simulations

The simulations were obtained from finite-difference time-domain (FDTD) calculations performed in a commercial software (Lumerical Solution, Inc., Canada) by Ph.D. student Mă Ruì. The overall

simulated structures were composed of three truncated cones, with dimensions and optical constants stated in Table 3.2. The top disk was placed in the centre of the structure as well at the edge. The structures were simulated on top of a glass substrate with refractive index of 1.5 in a vacuum background with refractive index of 1. It was used a plane wave from the vertical direction and the electric field was aligned with the *x*-axis, which corresponds to the offset direction of the top disk. The mesh size was 1 nm for every direction with the *x* and *y* being with a periodic boundary condition (300 nm) while the *z* direction was bounded by 32 perfectly matched layers. It was used a server with a RAM of 64 GB and the simulations took between 30 min to 1 h.

Table 3.2 - Simulated structure dimensions and reference for optical constants.

	Material	Inferior radius [nm]	Superior radius [nm]	Thickness [nm]	Reference
Top disk	Au	27.5	24	20	38
Middle disk	Al ₂ O ₃	61.5	61	3 and 6	39
Bottom disk	Au	65	61.5	20	38

4. **Results and Discussion**

4.1. Fabrication Steps

The desired structure is schematically depicted in Figure 4.1. Note that the top disk can be moved along the structure surface varying the deposition angle.



Figure 4.1 - Schematic cross-section of the final structure. A thin layer (3 nm) of Al_2O_3 (in grey) sandwiched by a big (120 nm diametre) bottom Au disk and a small (55 nm diametre) Au small disk, both having a 20 nm heigth (both in orange).

Figure 4.2 shows the polystyrene particles dispersed along a silicon substrate, on top of a PMMA layer while Figure 4.3 depicts the mask A) before and B) after the shrinking deposition. Although not desirable, Figure 4.3B has particles which were not removed on a previous step and some are aggregated. The presence of the particles by itself is not very important, it only means that there are going to be less structures on the sample's surface, but the aggregation should be avoided. However, it is possible to see that the holes' position in maintained and their diameter is successfully shrunk by comparing the holes' size to the original particles' size.

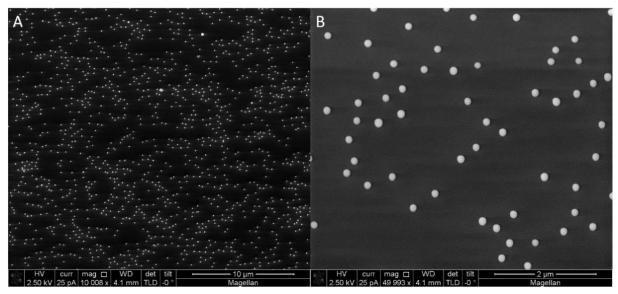


Figure 4.2 – 140 nm PSNPs spread over a PMMA surface with two different magnifications, at A) 10k times and B) 50k times. These images were obtained on a silicon subtrate and a lower voltage (2.5 kV) and nominal current (25 pA) to avoid charging as much as possible.

This aggregation could be due to insufficient UV/Ozone treatment as the lamp used might be weaker than expected. With a longer treatment time, the ozone would make more oxygen bonds with the polymer, resulting in a higher electrostatic force between the film and the polyelectrolytes.

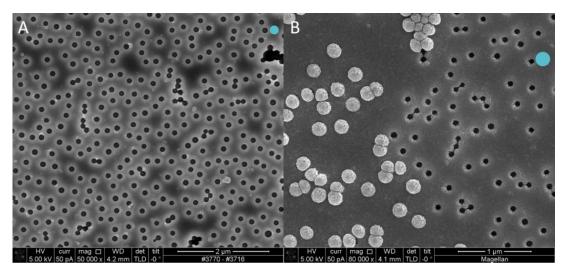


Figure 4.3 - Titanium mask used during the fabrication process A) before and B) after the extra titanium layers deposition. B) shows also some PSNPs which were not tape-stripped and some aggregation. These samples were not covered in Ti since the mask is already a conductive layer. The blue circles in both sides represent a 200 nm diametre circle in the respective scales.

The final structure depicted in Figure 4.4 is obtained after removing the polymer and the metal with acetone. It is represented in this figure samples with the top disk deposited at A) 0 ° and B) 6 °. It is possible to observe some defects that can happen during the structures' fabrication (besides the already discussed disk aggregation). In Figure 4.4A, there are a couple of structures that are slightly bigger than the others. Such result is unavoidable since the colloidal solution has some particles that may be bigger. On the other hand, in Figure 4.4B, there are some particles that are not complete or have something extra in the structure. This is caused by defects on the mask, where the holes may not have closed evenly and thus, the top disk was deposited in the wrong place while there is one which does not have any disk at all on top. Again, it is caused by the particles' size dispersion and, as the holes were being shrunk, this hole may have been completely closed, not allowing for a second gold deposition. However, whichever the case, and not accounting the aggregation observed in Figure 4.4A, since they are only two or three cases in the whole image, they will not affect considerably the extinction measurements.

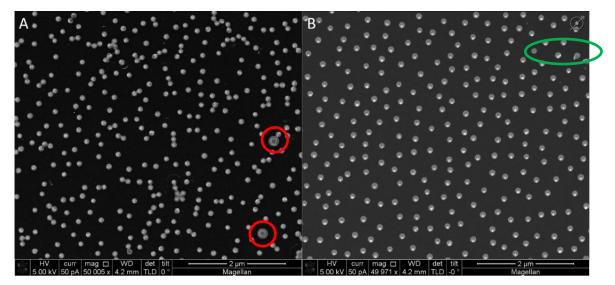


Figure 4.4 – SEM picture of the final structures after removing the sacrificial layer with acetone with the top disk deposited at A) 0 $^{\circ}$ and B) 6 $^{\circ}$. Almost every disk pair has approximately the same diameter. However, in A), a few may be of a different size, like the ones marked in red. In B), marked in green are some defective structures.

Through Figure 4.2 to Figure 4.4, it is possible to see that the pattern is maintained throughout the whole process as well as the top-bottom disks centre's distance. In fact, using ImageJ and a MATLAB script for several SEM pictures of the 6 ° deposition, the lower disk diameter is estimated on (118 ± 6) nm (of 730 particles analysed, taken from 3 pictures) and the upper disk diameter is estimated on (55 ± 6) nm (of 737 analysed particles from the same 3 pictures as the previous ones). It is important to note that all particles were assumed to be circular for these calculations. The deviation on the big disk size is in agreement with the relative deviation of the original particle size. As shown in Figure 4.4, there are some big particles without a small one on top. However, the fact that the script calculated more small particles than big ones has to do with the fact some small particles were broken and when processing the images, a small particle could be considered as two to correctly analyse the whole picture. Even with this limitation, the absolute standard deviation of both kind of disks are approximately the same, proving this a good method to consistently shrink the holes on the mask. It was also possible to determine the disks' centres of mass distance between the top and bottom using the same script in MATLAB, which is estimated at (27 ± 4) nm. Being this distance roughly half the small disk radius, it is thus shown mathematically that the top disk is close to the edge.

Then, to see how the individual disks would respond, samples with only the big disks and then only the small disks were fabricated. To ensure that the small disk would have the same size as if it were fabricated with the big gold disk, SiO_2 was deposited to replace the big gold disk. As mentioned before, Au has a sidewall angle of 11.7 ° while SiO_2 has an angle of 47.2 °. This means that, to replace a 20 nm thick disk with SiO_2 , it should be deposited 3.9 nm of the insulator material as suggested by Figure 4.5. The deposition rate used for this material was 0.3 Å/s.



Figure 4.5 - Schematic of the small disk fabrication. The materials used are the same except the bottom disk, which is 3.9 nm high SiO₂ (depicted in black) instead of Au.

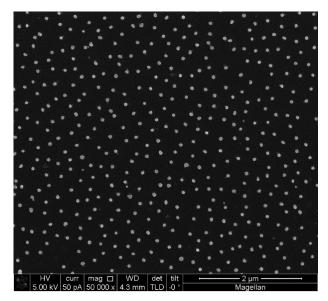


Figure 4.6 - SEM image of small disks on their own, using a SiO₂ layer to replace the big Au disk.

On the samples with small disks fabricated this way, it was observed a total of 2002 small disks with a diameter of (69 ± 8) nm. Although these disks are slightly bigger than the ones fabricated on top of the big gold disks, they are enough for the purpose intended. This increase may have to do with the SiO₂ itself, since it is a very difficult material to deposit using an e-beam evaporation technique (the observed deposition rate was not perfectly 0.3 Å/s) together with a low thickness which may have resulted in a different real thickness than desired. In this picture, it is more evident the non-circular shape of the small particles, a limitation of the mask-shrinking process.

Finally, the desired sensing structure was designed to have only the top disk exposed. Using a different etching machine, holes were etched on the quartz substrate, so it would be possible to deposit the big disk inside said hole. The following AI deposition would cover the disk's surface. Figure 4.7A shows a SEM picture of the holes (and part of the hole mask that remained on the sample) while Figure 4.7B shows the holes with the first layer of gold deposited.

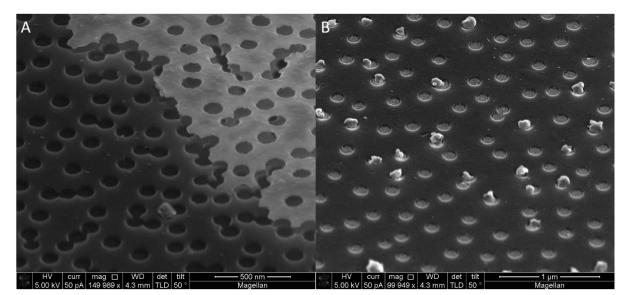


Figure 4.7 – SEM pictures of A) etched holes on quartz and B) etched holes filled with gold of 20 nm height, also on quartz. Both pictures were taken with the sample tilted at 50 °.

It is possible to observe that the holes follow the same pattern and size established by the PSNPs and the gold fits the hole. With the help of a functionality in the SEM software, the holes are roughly estimated to have a depth of 25 nm. More precise measurements can be obtained through Atomic Force Microscopy which was unavailable at the time. However, in Figure 4.7B, there are some features on top of the gold disks. These are possibly some quartz debris that fell over the holes. When the substrate is being etched, small particles of quartz are etched and will escape the bombardment site. While some of it might escape through the hole mask, some might stick to the polymer sidewalls and underneath the mask, and when the samples are lifted off, some of that residual quartz could fall over the holes. The nature of these debris could be further investigated through X-ray Photoelectron Spectroscopy (XPS) to assess what elements compose all the sample, and in case it is quartz, adjust the first etching step (PMMA etching) to allow a higher etching rate for PMMA sideways or spin-coat a thinner layer of the polymer.

Finally, in Figure 4.8, it is possible to see two full structures with the bottom disk inside the hole. Using this method, it is possible to do such a thing. There is a circular residue around the structure that is related to the polymer. It was very uncommon to appear on the samples' surface, but it can be properly removed with a plasma cleaning.

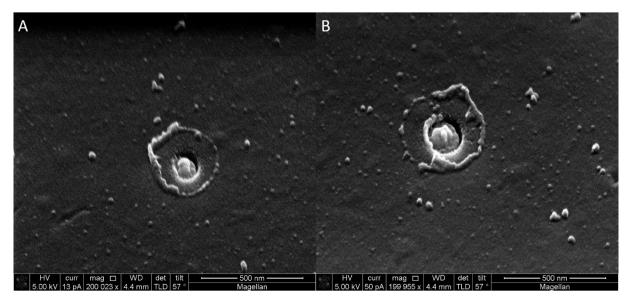


Figure 4.8 – Two nanosandwhich strucutres inside a hole made on the quartz substrate. The samples were tilted at 57 $^{\circ}$.

4.2. Extinction Measurements – Experimental and Simulations

The following spectra may show a discontinuity at 900 nm. It was generated by the equipment when changing the grating system to access different spectral range and should be ignored.

In Figure 4.9, it is shown the spectra for the individual disks, both the big disks (in black) on their own and the small disks (in red) made on top of a SiO_2 base.

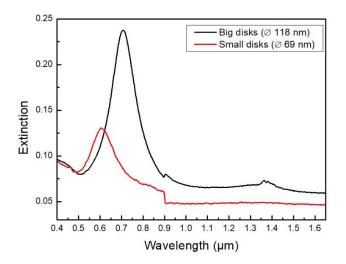


Figure 4.9 – Extinction spectra for individual disks, big (in black) with a diametre of 118 nm and small (in red) with a diametre of 69 nm. It is possible to see a difference in the peak position as well as extinction intensity. There is an additional artifact on the black line at around 1400 nm that also showed up in other samples made at the same time, possibly due to some humidity on the equipment, so it should also be ignored.

The difference in the peak position is purely due to the size of the disk and the number of electrons available to oscillate. The relevant aspect to discuss, however, is the signal given by both disks. The smaller disk has a much lower signal than the big disk. In this case, it is not the different number of disks in each case that causes this, as the big disk samples had an average particle density of (8.2 ± 0.2) particles/µm² while the small disks samples have an average density of (13.0 ± 2.2) particles/µm². The lower signal can prove difficult to monitor the wavelength peak change due to a lower signal to noise ratio. This is the reason to try a structure which can use the high signal that comes from the bigger interaction with the incident light from the big disk and the high sensibility from the smaller disk.

For that, a full structure on glass was fabricated and had its light extinction measured, with the top disk in the centre of the structure and by the edge of the bottom disk, with results shown in Figure 4.10, both experimental and simulated.

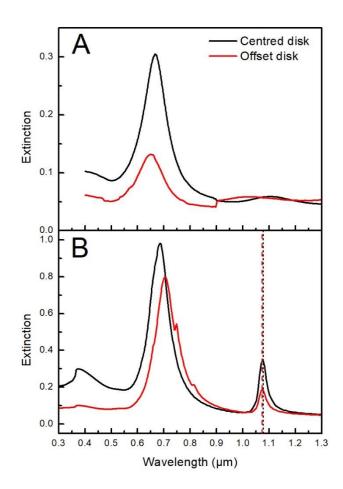


Figure 4.10 - A) Experimental extinction spectra for full structures and B) simulated transmission spectra for the the same structures. In both, the black line corresponds to the top disk centrered with respect to the bottom one and the red corresponds to the offset disk, placed at the edge.

First, the simulated spectra for the offset disk case has a lower intensity than the centred disk, which means it is easier to excite the plasmonic modes in the symmetric case rather than the asymmetric structure, possibly due to the symmetry. As for the experimental intensity decrease, this is mostly due to the lower number of structures present on this particular sample compared to the centred disk sample.

Starting the peak analysis from the low energy (LE) peaks (i.e. longer wavelengths, at around 1075 nm), the simulation suggests that there is no difference on the optical response of the structures when moving the top disk around the structure apart from a minimal shift (indicated by the dashed lines), which will be further discussed when looking at the field plots. This peak is caused by a purely plasmonic gap mode on the insulator layer and the energy confinement inside the gap. Only the shift's direction occurs in the experimental set, not the magnitude of it. It is suggested that the FDTD model cannot replicate the magnitude of the blue-shift because it only simulates on a single, well defined structure, which does not happen experimentally. The disks are subjected to process variability on their geometry, more prominently the top disk, heavily influencing the peak position. Also, the mismatch on the peak positions may be due to the overestimation of the oxide's refractive index on the simulation, as the software does not take into account quantum effects that may occur when dealing with structures this thin⁸.

Moving on to the high energy (HE) peak, the results are seemingly contradictory. While the experimental set shows a blue-shift, the simulation reveals a red-shift when the disk is moved around. The red-shift on Figure 4.10B is that the Z component of the electric field (Figure 4.13A) is not symmetric along the surface that corresponds to the gap, which would suggest that the electrons would be more spread over in such a way, so it could lower the system's overall energy. Also, this HE peak shows some peak/dip features on the offset structure in the simulated spectrum. These are due to the excitation of higher order multipoles through the energy given by the overall structure, resulting in a Fano resonance^{8,15}. The fact that they only show up in the offset structure implies that it is easier to excite these multipoles when the disk is not centred. Its absence on the experimental set experimental set may be caused by the experimental polydispersity, which would broaden and smoothen the sharp peak (since it would happen at different wavelengths for different structures). Once again, the simulation deals with only one structure while the actual experimental structures have some degree of variability (different radii between disks, for instance). Due to this absence, no further study was made on such peaks.

The blue-shift on Figure 4.10A may be caused by imperfect structures. Recalling the distance calculations, (27 ± 4) nm between the centres the big and small disks, some disks have fallen over the bottom ones, making one complex structure instead of two separate disks.

In the simulation, it is also shown a peak at around 375 nm, which corresponds to the interband transitions of gold⁴⁰. The experimental spectra also show an increasing extinction towards these wavelengths, but the measurements were only performed until 400 nm.

Next, in Figure 4.11, it is represented the spectra for the structure with the top disk in the centre, only varying the alumina layer thickness from 3 nm to 6 nm.

Again, starting from the LE peak, there is good agreement between the shift's direction as the oxide thickness increases, but not on the amount that it changes. Once again, the discrepancies on the peak's position are maybe due to the overestimation of the oxide's refractive index by the software. Considering the bonding configuration in the hybridisation model, it would mean that the electron's oscillation in the top disk is out-of-phase regarding the bottom disk. As such, the net dipole moment for the whole

structure would be reduced. As the separation increases, the disks are not as strongly coupled as they were, resulting in a weaker cancelation and a higher dipole energy⁸.

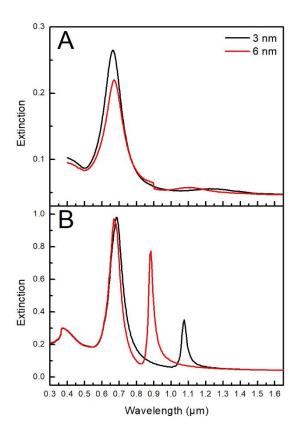


Figure 4.11 - A) Experimental extinction spectra for full structures and B) simulated transmission spectra for the the same structures. In both, the black line corresponds to a disk separation by AI_2O_3 of 3 nm and the red line to a disk separation of 6 nm.

As for the HE peak, there is again a disagreement between the shift's direction. However, it should be taken in consideration that it is highly likely that the upper disk on the 6 nm thick oxide structure may be smaller than in the 3 nm thick disk as an extra deposition occurred (and further oxidation, which shrunk the hole even more); the simulated structure may have not been properly designed, giving a different overall geometry.

4.3. FDTD Field Plots

Figure 4.12 and Figure 4.13 show electric field distribution plots for the studied structures. The *xy*-plane contains the bottom face of the bottom gold disk and the disks are stacked along the *z*-axis, coinciding with the propagation of the incident light. In Annexe C – Additional Electric Field Plots it is possible to see the same plots in logarithmic scale instead.

Figure 4.12 shows the *z*-component of the electric field obtained for all simulated scenarios for the respective LE peaks. This component was chosen as it can hint about the charge distribution inside the materials. As predicted, this peak is governed mainly by a plasmonic gap mode, resulting from the bonding configuration of both disks. On both symmetric configurations (Figure 4.12D and F), the field enhancement is symmetric on the sign distribution. The small shift seen in Figure 4.10B can be possibly

explained by the fact that the red component is slightly shorter than the blue one. This inequality may imply a different charge distribution on the disks, which could lead to an increase on the gap's energy. The disks' electrons can only oscillate between the metal boundary, they cannot leave the material. As such, the top disk's one cannot oscillate further away from the centre of the bottom disk, since that is where the top disk ends, whereas the bottom disk's electrons can oscillate beyond this point, leading to a more spread over electron distribution towards the opposite side of the top disk. This fact may cause the uneven gap electric field distribution.

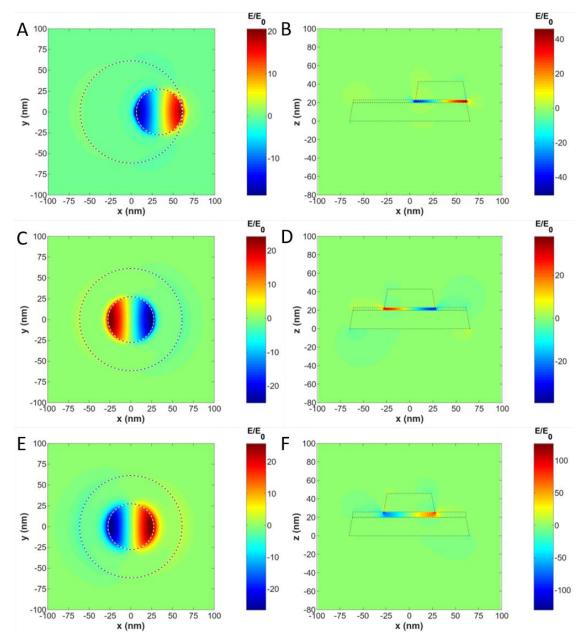
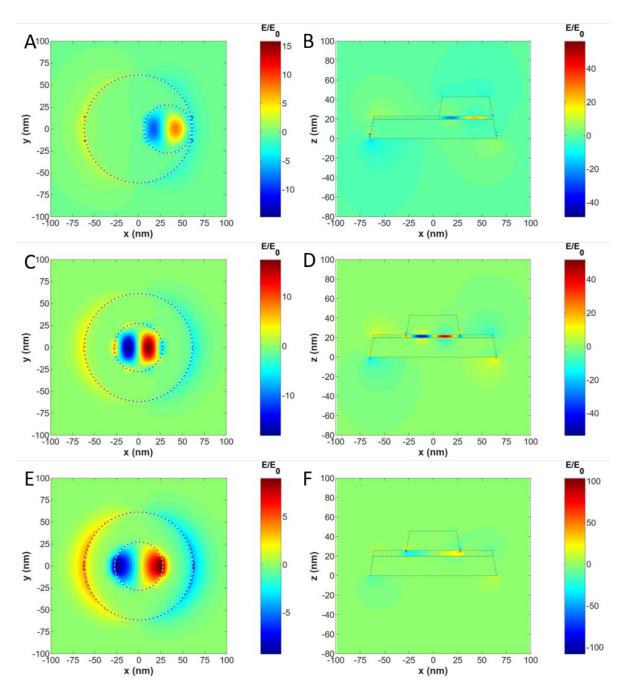


Figure 4.12 – *z*-component electric field plots obtained for the respective low energy peak wavelength of the A) and B) offset structure with 3 nm spacer, C) and D) centered structure with 3 nm spacer and A) and B) centred structure with 6 nm spacer. A), C) and E) are obtained from the bottom disk/alumina interface while B), D) and F) is a cross-section that goes through the centre of the top disk. The dashed lines represent the perimeter of the different components of the structure.

As for the oxide thickness influence, the field is less confined on the gap, although the overall enhancement is superior on the thicker oxide (note that the scales are different).

It should be considered that the scale on Figure 4.12F goes to around ±125 because of the small region on the spacer/top disk interface. This happens because the software breaks down the structures in small cubes, and this structure in particular has a sidewall, which will make sharp edges, known to be enhancement hotspots. Therefore, although this structure's gap has a superior field enhancement (the absolute value goes up to around 70), even higher enhancements for individual pixels are achieved but are not physically meaningful.



Next, Figure 4.13 is the same as Figure 4.12, this time at the HE peak wavelength.

Figure 4.13 – Z-component electric field plots obtained for the respective high energy peak wavelength of the A) and B) offset structure with 3 nm spacer, C) and D) centered structure with 3 nm spacer and A) and B) centred structure with 6 nm spacer. A), C) and E) are obtained from the bottom disk/alumina interface while B), D) and F) is a cross-section that goes through the centre of the top disk. The dashed lines represent the perimeter of the different components of the structure.

Again, and contrary to expected, there is also a high field enhancement on the spacer layer. However, there is also enhancement on the vicinity of the structures (more prominent near the edges), leading to a net dipole moment for the overall structure. So, it can be concluded that the HE peak is given by the interaction between the gap mode and antibonding mode.

The electric field enhancement near the disks (and outside the gap) have approximately the same enhancement factor on the *z* direction (around 5), indicating that both position on the top disk and spacer thickness don't have much influence on the field's enhancement. The gap however seems to be influenced by both parameters, and it is more intense on the centre disk structure separated by 3 nm thick spacer (Figure 4.13D), whereas on the other two configurations, the influence is of the same importance, even though the field shape is not symmetric. This asymmetry may have to do with the charge distribution inside the metallic materials.

As the biosensing activity would happen around the small disk, the HE peak should be monitored as it is influenced by the overall structure's net dipole. Taking into account this original idea, the best structure to be used as a biosensor would be the symmetric structure with a 3 nm separator layer, as it is the one that has a higher electric field enhancement around the structure's boundary. However, as it was previously mentioned, the gap mode has also a big influence on the peak's intensity, and in the thinner oxide scenarios, it is more important. This may suggest that the gap mode should be used as the biosensing medium. To make use of this, another configuration should be used (for example a metal-insulator-metal structure sideways) as if the alumina layer is partially etched, the top disk may not have a support and fall down to the bottom disk.

5. Conclusions and Future Perspectives

This work intended to develop a fabrication procedure to a stacked disk pair of different diameters for biosensing applications. So far, to use only the top disk as the sensing structure, the fabrication process has shown promising results, since it seems to be possible to bury the bottom disk in a quartz hole underneath an alumina layer. The structure that should be further studied to learn about its biosensing capabilities should be the thin insulator layer (3 nm) with the top disk on the centre. This has shown to have a higher electric field enhancement around the structure compared to the others studied.

To make sure that the bottom disk is in fact isolated, one could deposit the bottom disk and the aluminum layer and oxidise it and immerse the sample in an alkanethiol solution since they should bind to gold. The sample would then be inspected through XPS and it is desired the absence of these alkanethiols.

A next approach to study the structure's potential use as a biosensor would be to use alkanethiols again, but with different carbon lengths and make extinction spectra. The idea would be to see how much the peak would shift with different refractive index in a thin film case rather than bulk surrounding media. In principle, the HE peak should be the one to be monitored. Not only because it is the one with higher intensity, but the LE peak is mainly related to the gap mode, where the biosensing will not happen.

Another important aspect is the optimisation of the entire process. As seen in the fabrication process, some issues have come up, specially the substrate etching process. First it is important to know the nature of the debris observed in Figure 4.7B, possibly through XPS. If in fact those debris are residual amorphous SiO₂ from the substrate, the polymer should be thinner to maximise the amount of SiO₂ that leaves through the hole or use other polymer etching parameters so that the sidewall etching can be higher and for that reason, some of the silica that sticks to the wall is further from the disk and lower the probability that falls over the structure.

As simulation goes, it is relevant to obtain charge distribution to further understand the field plots and the optical response of all structures. It may also be of some importance to make new FDTD simulations of the structure inside a quartz hole to predict how would the surrounding quartz may influence the optical response of the sample, similar to the ones shown in Figure 4.8, since those would be the structures to be used as biosensors.

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6. References

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7. Annexes

7.1. Annexe A – ImageJ Processing

To turn SEM pictures into sets of data regarding each disk's coordinates, average diameter and area, ImageJ was used. Starting from a SEM image (Figure 7.1), saved as an 8-bit .tif file, a conversion to a black and white picture is needed, where it is shown with the disks in black and all the background and SEM information bar at the bottom in white. This was accomplished by using the threshold function (Figure 7.2), which allows to choose between which bit values should be included in a particle or not. In this example, the particles positioned touching the edge are erased and therefore not considered because the software cannot know if it is half or a quarter of a particle, giving wrong information about the particles' area and most importantly, the coordinates for their centres of mass.

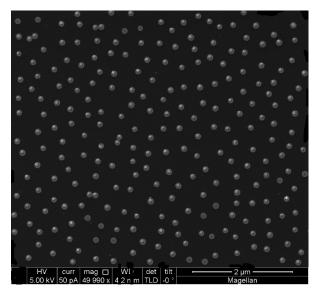


Figure 7.1 - Starting SEM picture for ImageJ analysis. It has some marks on some particles at the edge (near the information bar) to further exclude them on the analysis.

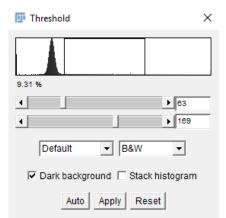


Figure 7.2 – 'Threshold' sub-menu. The histogram represents the 'colour' distribution by bit number (from 0 to 255) of the picture and the pixels with the 'colour' number between the range (in this case, 63 and 169) will turn black while the rest will turn white.

This conversion to a binary image is done for big and small particles. The small particles have a higher bit value (i.e. are whiter) than the bottom ones because of the edge effect that naturally occurs inside the microscope. However, the centre of the small disks may have a similar 'colour' than the bottom ones and may be excluded doing the threshold selection. The software has an option to include the holes, so it is only relevant to make circumferences and not whole circles.

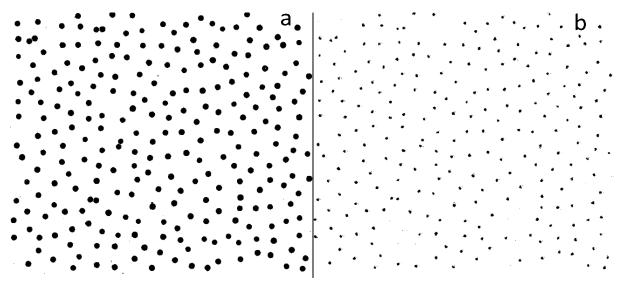


Figure 7.3 – Binary pictures obtained from Figure 7.1 for a) big particles and b) small particles.

From this binary picture, ImageJ will analyse particles (Figure 7.4). This is done by selecting a size range (whether in pixel units or actual distance in case a scale was set) and the circularity (i.e. how close to a perfect circle the particle looks like) of these isolated islands. For this work, both 'Exclude on edges' and 'Include holes' were selected for the reasons already stated before. This will generate a .txt file giving all the relevant information on each particle (which could be changed in the 'Set Measurements' tab) and another image file (Figure 7.5) which gives the number of the particles and their outline (using the option 'Show: Outlines'). From here, the data obtained is then statistically processed.

Analyze Particles			×
Size (µm^2):	D-Infinity units		
Circularity:	0.00-1.00		
Show:	Outlines	•	
Display results Exclude on edges			
Clear results		Include holes	
Summarize		Record starts	
🗖 Add to Manager 🛛 🗖 In situ Show			
	ОК	Cancel	Help

Figure 7.4 – 'Analyze Particles' sub-menu. The islands' size can be defined to ignore some random pixels which could not be excluded with threshold selection.

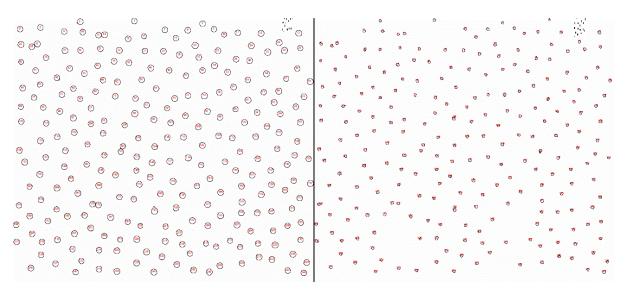


Figure 7.5 - Outline pictures obtained from Figure 7.3 for a) big particles and b) small particles. Note that every particle has a number and this number is associated with a set of measures regarding to that particle in a separate .txt file.

7.2. Annexe B – MATLAB code

7.2.1. Function ParticleDistance

```
%fB = File with big particles data,
%fs = File with small particles data,
%date = Folder name for directory purposes.
function ParticleDistance%(fB,fs,date)
   %To save the files names to give to the ones being generated.
name = strtok(fB,' ');
direc = fullfile('C:','Users','W10','OneDrive','Tese','Data','SEM Images');
direc = fullfile(direc,date,'Info on Small Disks');
   fB = fullfile(direc,fB);
   fs = fullfile(direc,fs);
   %Matrices to store the data on files fB and fs.
   B = [];
   s = [];
   %Puts data for processing.
   fBid = fopen(fB, 'r');
line = fgetl(fBid);
   while ~feof(fBid)
       line = fgetl(fBid);
        B = [B ; str2num(line)];
   end
   fclose(fBid);
   fsid = fopen(fs,'r');
   line = fgetl(fBid);
   while ~feof(fsid)
        line = fgetl(fsid);
        s = [s ; str2num(line)];
   end
   fclose(fBid);
   %Match the particles and sorts them by Big Particle number.
   M = Match(B, s);
   %p = number of pairs matched. It can be a bigger number than the number
   %of particles existing. A big particle may have 2 small particles on
   %top, for example.
   p = size(M, 1);
   Tells which particles don't have a match, {\tt N} for big, n for small
   %particles. N says which big particles that don't have a small one on
%top of it and n says which particles are in the middle of nowhere or
    %really afar from the big one. Check why is there a matrix n.
   N = NotMatch(B,M(:,1));
   n = NotMatch(s, M(:, 2));
   %Save results onto 3 external files on the same directory as the
%originals, PP (paired particles), UB (unmatched big) and Us (unmatched
   %small).
   Name = strcat(name, '_', 'PP.txt');
   NF = fullfile(direc, Name);
   PPid = fopen(NF,'w');
title = sprintf('%i Pairs Matched \n',p);
   fprintf(PPid, title);
fprintf(PPid, 'Big P \t Small P \t Distance (pxl) \t Area %% on top of Big Particle \n');
    for i = 1 : size(M, 1)
        a = M(i, 1);
        b = M(i, 2);
        c = M(i, 3);
        d = M(i, 4);
        str = sprintf('%03i \t %03i \t %.3f \t %.3f \n',a,b,c,d);
        fprintf(PPid,str);
   end
   fclose(PPid);
   p = size(N,1);
   P = size(B, 1);
   pr = p/P*100;
   Name = strcat(name, ' ', 'UB.txt');
   NF = fullfile(direc, Name);
   UBid = fopen(NF,'w');
title = sprintf ('%i out of %i (%.lf percent) \nbig particles do not have a match \n',p,P,pr);
   fprintf(UBid, title);
   for i = 1 : p
```

```
a = N(i, 1);
       str = sprintf('%03i \n',a);
       fprintf(UBid,str);
   end
   fclose(UBid);
   p = size(n,1);
   P = size(s, 1);
   pr = p/P*100;
   Name = strcat(name, '_', 'Us.txt');
   NF = fullfile(direc,Name);
   Usid = fopen(NF,'w');
title = sprintf ('%i out of %i (%.1f percent) \nsmall particles do not have a match \n',p,P,pr);
   fprintf(Usid, title);
   for i = 1 : size(n,1)
       a = n(i,1);
       str = sprintf('%03i \n',a);
       fprintf(Usid,str);
   end
   fclose(Usid);
end
```

7.2.2. Function Match

```
%P is a matrix that will contain the ID number of the big particles that
%match the small particles, the distance between their centres of mass and
%how much area of the small particle is on top of the big one. This area
%calculation is made assuming the particles are perfect circles.
function P = Match(M1,M2)
P = [];
for i = 1:size(M1,1)
     x1 = M1(i, 3);
     y1 = M1(i, 4);
     for j = 1:size(M2,1)
         x2 = M2(j,3);
         y2 = M2(j, 4);
         %Two particles more than 8.5 pxl (~50 nm) apart are not a match.
         d = 8.5; %pxl
          if abs(x1 - x2) < d && abs(y1 - y2) < d
               %Distance between the two particles centre of mass.
              x = x2 - x1;
               y = y2 - y1;
              d = sqrt(x^2 + y^2);
               Average radii for the particles (in pxl).
              R = (M1(i,6) + M1(i,7))/4;
r = (M2(j,6) + M2(j,7))/4;
               %Is the small particle completely on top of the big one?
               if d <= R-r %It is all inside, so 100%
    A = 100;</pre>
              elseif d >= R+r %Its all outside, 0%
A = 0;
               else %Tricky formula
                   a = r^{2} * acos((d^{2}+r^{2}-R^{2})/(2*d*r));
                    a = 12 a cos((d^{2}H^{2}-r^{2})/(2*d*R)); 
b = R^{2} a cos((d^{2}H^{2}-r^{2})/(2*d*R)); 
c = (sqrt((-d+r+R)*(d+r-R)*(d-r+R)*(d+r+R))) /2; 
                   A = a+b-c;
                   Ac = pi*r^2;
                    %In percentage
                   A = (A/Ac) * 100;
              end
              P = [P; M1(i, 1), M2(j, 1), d, A];
         end
    end
end
%Sorts by number of the big particles.
P = \text{sortrows}(P, 1);
end
```

7.2.3. Function NotMatch

```
%Q will store particles # without a match, like a complementary of P in the
%universe M
function Q = NotMatch(M,P)
a = size(M,1);
b = size(unique(P(:,1)),1);
c = abs(a-b);
Q = zeros(c,1);
m = 0;
for i = 1:size(M,1)
n = 0;
for j = 1:size(P,1)
if P(j) == M(i,1)
%if there is a match, saves the line and stops the cycle to
%move on
n = i;
break
end
end
if n == 0 %If there is not a match, save the result on Q
m = m+1;
Q(m) = M(i,1);
end
end
Q = sortrows(Q);
end
```

7.3. Annexe C – Additional Electric Field Plots

The following field plots (Figure 7.6 and Figure 7.7) are the same as Figure 4.12 and Figure 4.13 respectively, represented in a logarithmic scale instead.

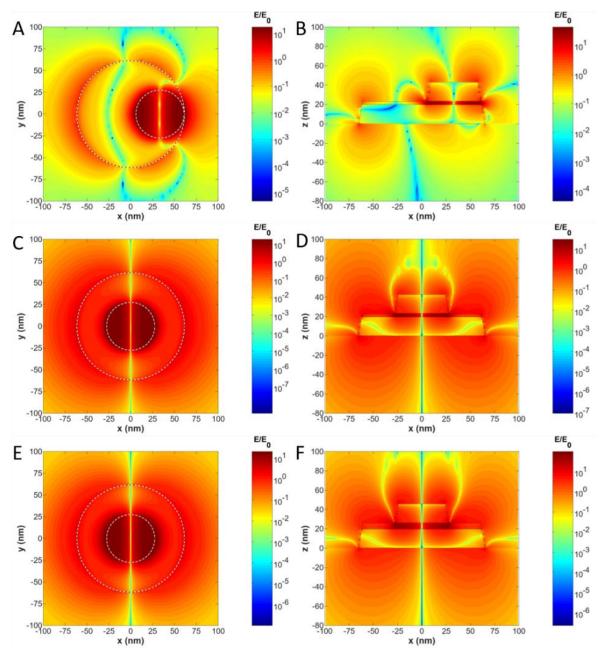


Figure 7.6 - z-component electric field plots obtained (in logarithmic scale) for the respective low energy peak wavelength of the A) and B) offset structure with 3 nm spacer, C) and D) centered structure with 3 nm spacer and A) and B) centred structure with 6 nm spacer. A), C) and E) are obtained from the bottom disk/alumina interface while B), D) and F) is a cross-section that goes through the centre of the top disk. The dashed lines represent the perimeter of the different components of the structure.

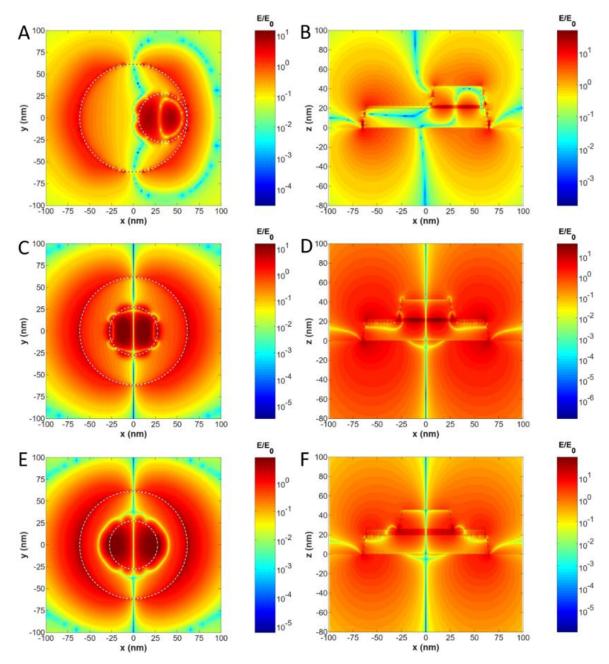


Figure 7.7 - *z*-component electric field plots obtained (in logarithmic scale) for the respective high energy peak wavelength of the A) and B) offset structure with 3 nm spacer, C) and D) centered structure with 3 nm spacer and A) and B) centred structure with 6 nm spacer. A), C) and E) are obtained from the bottom disk/alumina interface while B), D) and F) is a cross-section that goes through the centre of the top disk. The dashed lines represent the perimeter of the different components of the structure.